



8ETH03
8ETH03S
8ETH03-1

Ultrafast Rectifier

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature


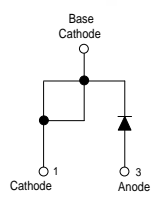

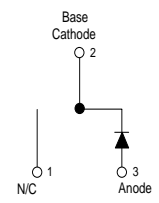

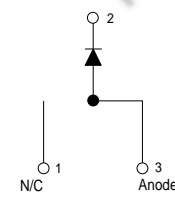
$t_{rr} = 35ns$
$I_{F(AV)} = 8Amp$
$V_R = 300V$

Description/ Applications

International Rectifier's 300V series are the state of the art Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and Ultrafast recovery time. The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics. These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Repetitive Peak Reverse Voltage	300	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 155^\circ C$	8	A
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ C$	100	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ C$

Case Styles		
<p>8ETH03</p>   <p>TO-220AC</p>	<p>8ETH03S</p>   <p>D²PAK</p>	<p>8ETH03-1</p>   <p>TO-262</p>

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _r Breakdown Voltage, Blocking Voltage	300	-	-	V	I _R = 100μA
V _F Forward Voltage	-	1.0	1.25	V	I _F = 8A
	-	0.83	1.00	V	I _F = 8A, T _J = 125°C
I _R Reverse Leakage Current	-	0.02	20	μA	V _R = V _R Rated
	-	6.0	200	μA	T _J = 125°C, V _R = V _R Rated
C _T Junction Capacitance	-	31	-	pF	V _R = 300V
L _S Series Inductance	-	8	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_C = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	-	35	ns	I _F = 1A, di _F /dt = -50A/μs, V _R = 30V
	-	27	-		T _J = 25°C
	-	40	-		T _J = 125°C
I _{RRM} Peak Recovery Current	-	2.2	-	A	I _F = 8A di _F /dt = -200A/μs V _R = 200V
	-	5.3	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	30	-	nC	T _J = 25°C
	-	106	-		T _J = 125°C

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	175	
R _{thJC} Thermal Resistance, Junction to Case Per Leg	-	1.45	2.5	°C/W
R _{thJA} ^① Thermal Resistance, Junction to Ambient Per Leg	-	-	70	
R _{thCS} ^② Thermal Resistance, Case to Heatsink	-	0.2	-	
Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

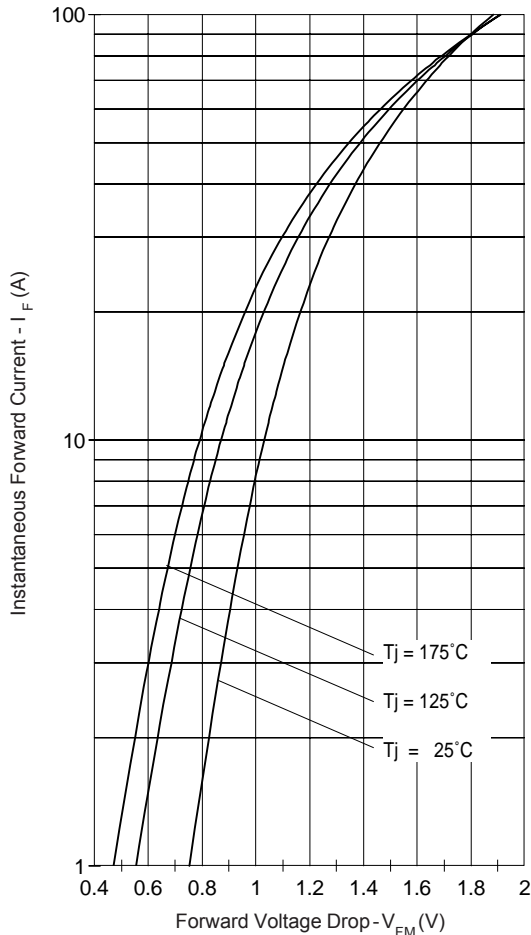


Fig. 1 - Typical Forward Voltage Drop Characteristics

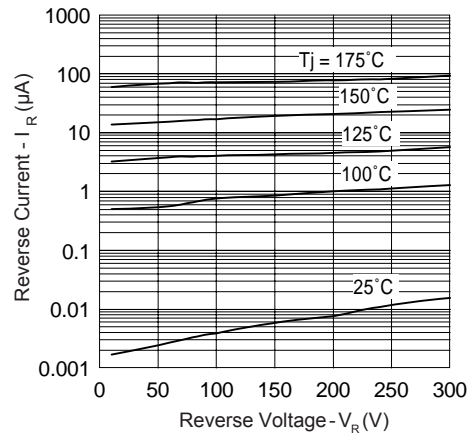


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

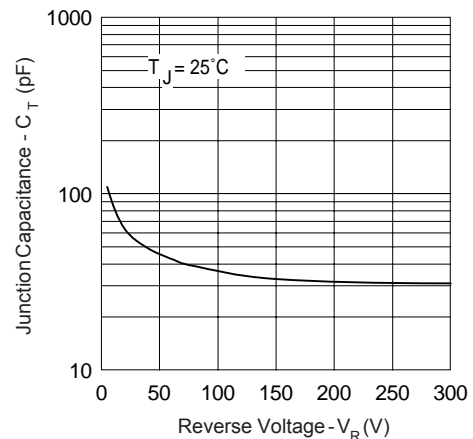


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

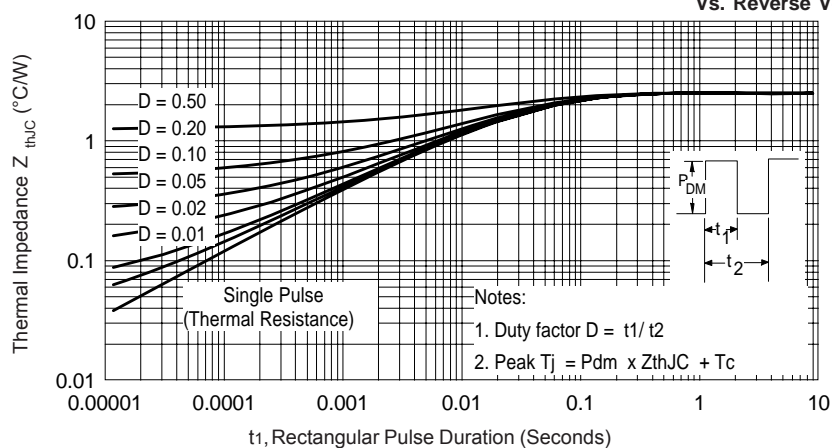


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

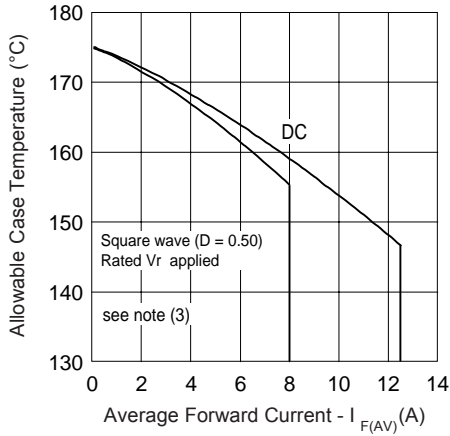


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

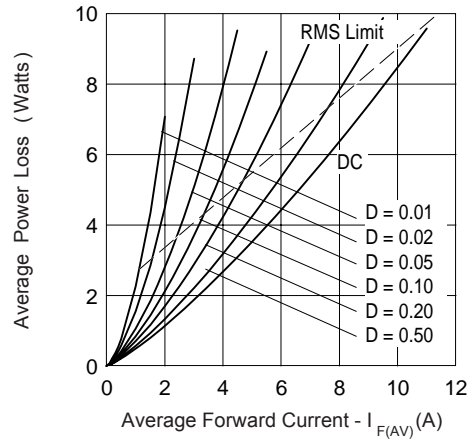


Fig. 6 - Forward Power Loss Characteristics

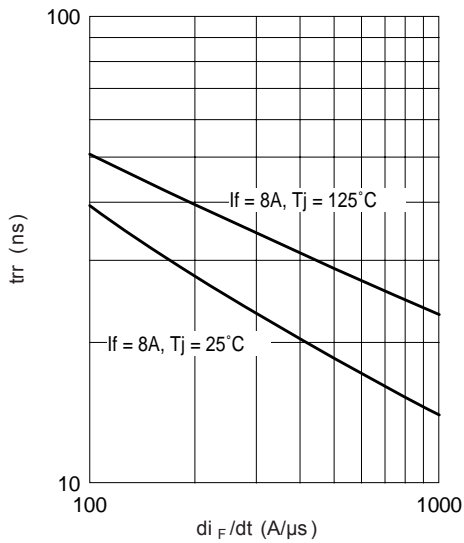


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

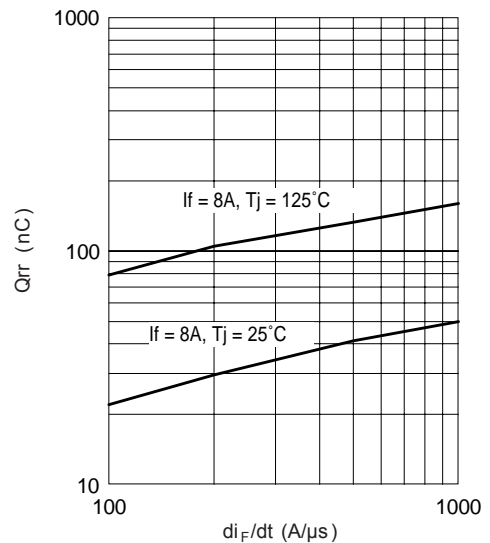


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

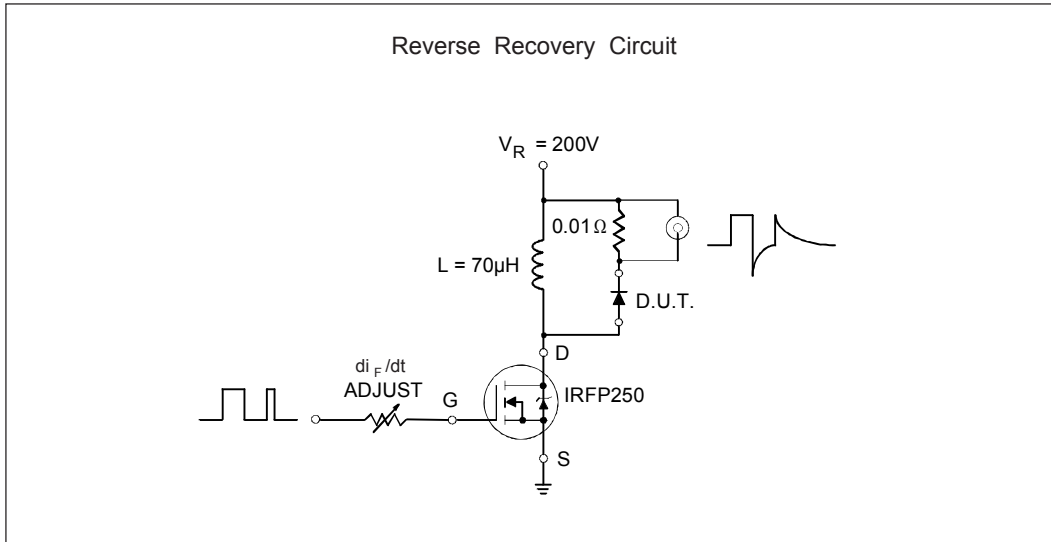


Fig. 1 - Reverse Recovery Parameter Test Circuit

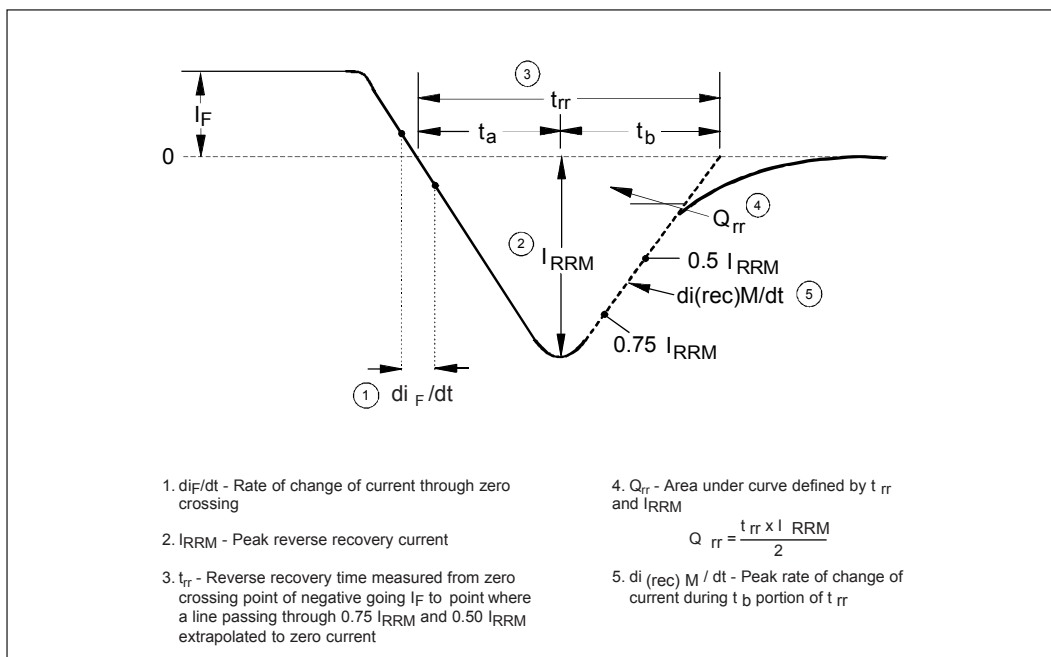
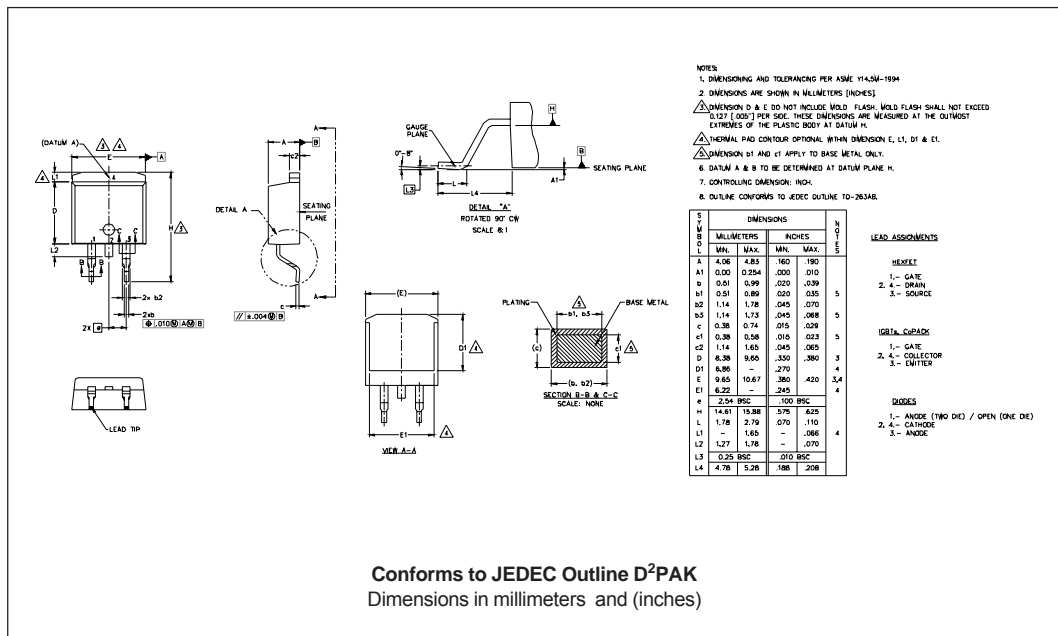
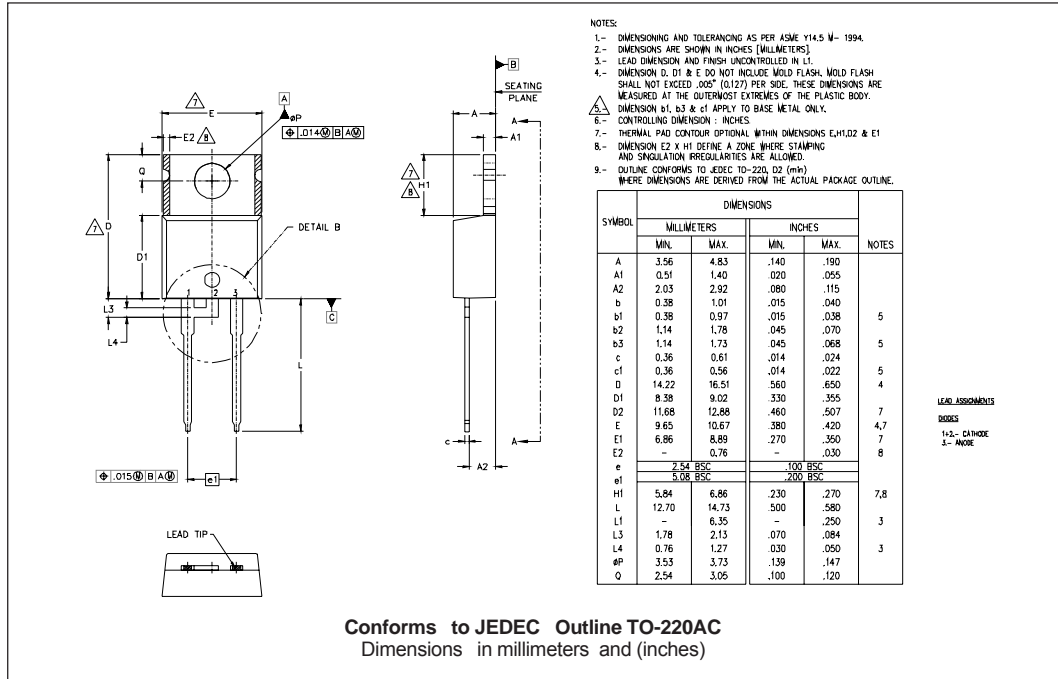
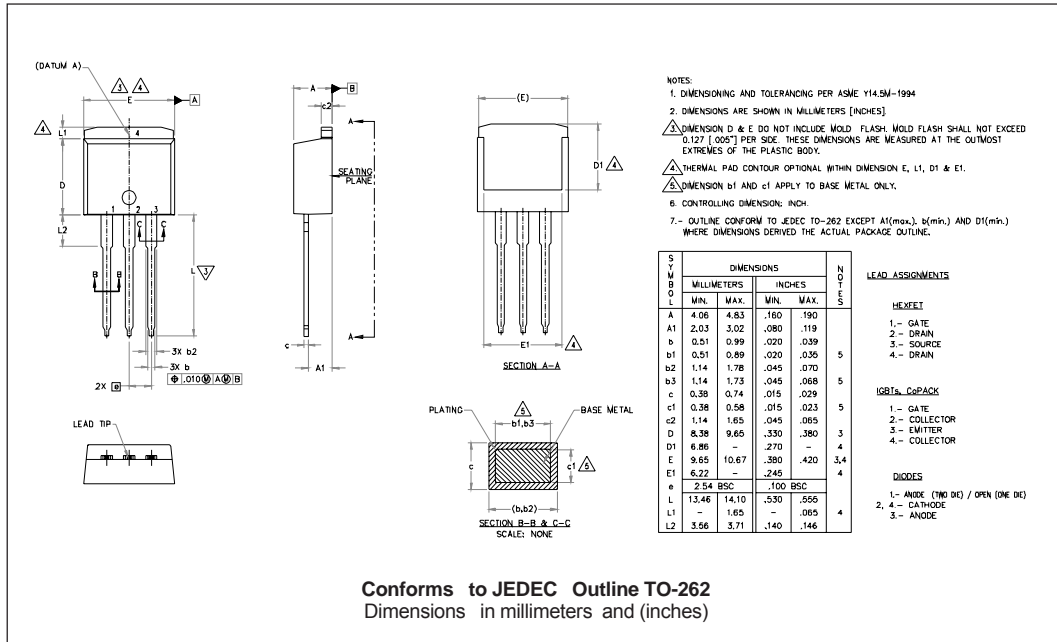


Fig. 2 - Reverse Recovery Waveform and Definitions

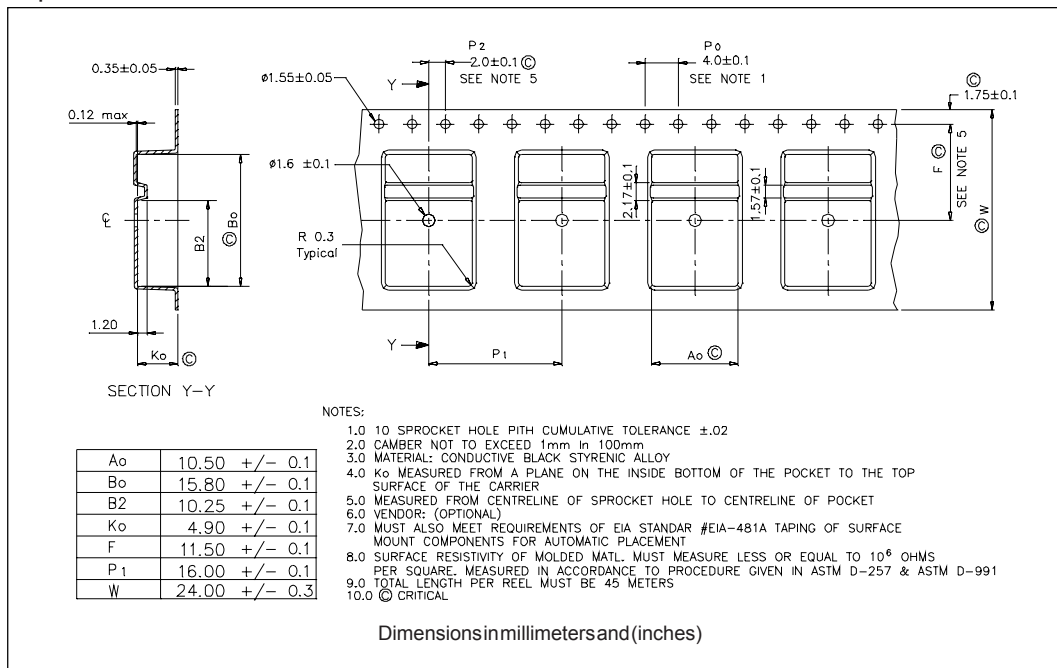
Outline Table



Outline Table



Tape & Reel Information



Part Marking Information

<p>TO-220AC</p>	<p>EXAMPLE: THIS IS A 8ETH03 LOT CODE 1789 ASSEMBLED ON WW 19, 2001 IN THE ASSEMBLY LINE "C"</p>	<p>INTERNATIONAL RECTIFIER LOGO</p> <p>PART NUMBER</p> <p>DATE CODE YEAR 1 = 2001 WEEK 19 LINE C</p> <p>ASSEMBLY LOT CODE</p>
<p>D²PAK</p>	<p>EXAMPLE: THIS IS A 8ETH03S LOT CODE 8024 ASSEMBLED ON WW 02, 2000 IN THE ASSEMBLY LINE "L"</p>	<p>INTERNATIONAL RECTIFIER LOGO</p> <p>PART NUMBER</p> <p>DATE CODE YEAR 0 = 2000 WEEK 02 LINE L</p> <p>ASSEMBLY LOT CODE</p>
<p>TO-262</p>	<p>EXAMPLE: THIS IS A 8ETH03-1 LOT CODE 1789 ASSEMBLED ON WW 19, 1999 IN THE ASSEMBLY LINE "C"</p>	<p>INTERNATIONAL RECTIFIER LOGO</p> <p>PART NUMBER</p> <p>DATE CODE YEAR 9 = 1999 WEEK 19 LINE C</p> <p>ASSEMBLY LOT CODE</p>

Ordering Information Table

Device Code																	
	<table border="1" style="margin: auto;"> <tr> <td style="padding: 5px;">8</td> <td style="padding: 5px;">E</td> <td style="padding: 5px;">T</td> <td style="padding: 5px;">H</td> <td style="padding: 5px;">03</td> <td style="padding: 5px;">-1</td> <td style="padding: 5px;">TRL</td> <td style="padding: 5px;">-</td> </tr> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> <td style="text-align: center;">⑦</td> <td style="text-align: center;">⑧</td> </tr> </table>	8	E	T	H	03	-1	TRL	-	①	②	③	④	⑤	⑥	⑦	⑧
8	E	T	H	03	-1	TRL	-										
①	②	③	④	⑤	⑥	⑦	⑧										
1	- Current Rating (8 = 8A)																
2	- E = Single Diode																
3	- T = TO-220																
4	- H = HyperFast Recovery																
5	- Voltage Rating (03 = 300V)																
6	- None = TO-220AC S = D ² Pak -1 = TO-262 Option FP = TO-220 FULLPACK																
7	- None = Tube (50 pieces) TRL = Tape & Reel (Left Oriented - for D ² Pak only) TRR = Tape & Reel (Right Oriented - for D ² Pak only)																
8	- • none = Standard Production • PbF = Lead-Free																

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.



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